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Stefano Curiotto, Ali El-Barraj, Fabien Cheynis, Pierre Müller, Frédéric Leroy. Motion dynamics of Si (100) positive and negative islands under electromigration and thermomigration. Journées Surfaces et Interfaces, Jan 2020, Paris, France. 2020. hal-02468958

#### HAL Id: hal-02468958 https://hal.science/hal-02468958v1

Submitted on 6 Feb 2020

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# Motion dynamics of Si (100) positive and negative islands under electromigration and thermomigration

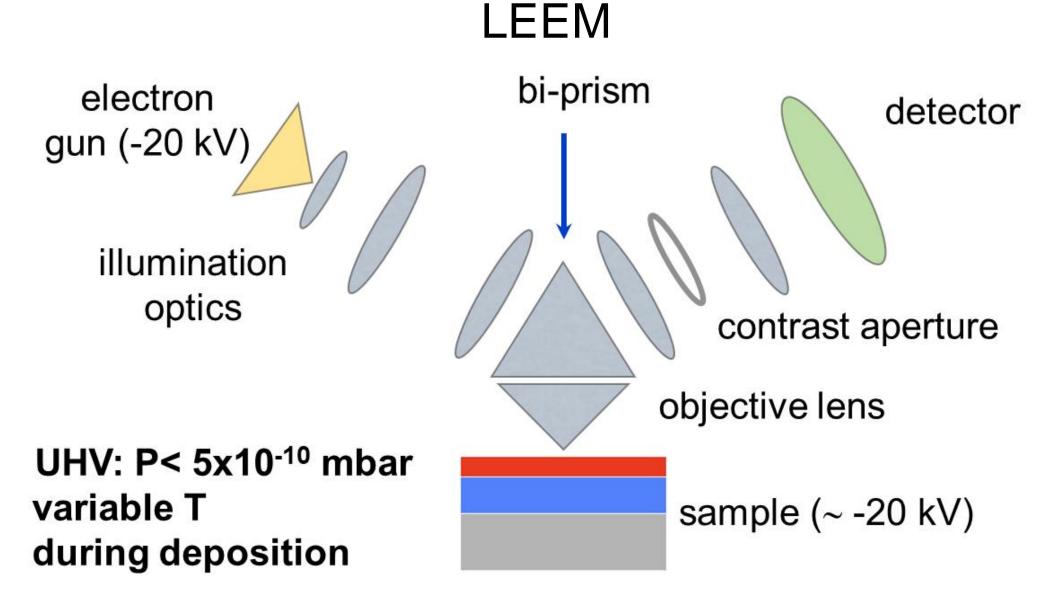
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Mass transport processes play an important role in nano devices. They determine the morphology and the stability of a working device, and eventually its lifetime. When a direct electric current is applied to a material, it affects the mass transport by adding a bias to the atomic diffusive motion. This effect, called electromigration, can play an important role on the dynamics and the morphological stability of nanostructures at surfaces. In this work we have studied the motion of single-step holes and islands under the effect of an electric field on Si(100), in real time, by Low Energy Electron Microscopy (LEEM). The details of the motion depend on the strong diffusion anisotropy of the Si dimer rows. Studying the velocity and the shape of the nanostructures, we discuss a model to explain and guide the motion of holes and islands.

The manipulation of nanostructures is an important challenge for nanoelectronics and nanofabrication technologies. External fields and thermal gradients are natural candidates to move and control the nanostructure position on a surface. Particularly promising is the use of electric fields to induce mass transport in specific directions, phenomenon known as electromigration (EM).

The elementary process of **electromigration** of an atom on a surface (adatom) is well known: the electric current biases random diffusion inducing mass transport in specific directions. The motion of many adatoms results in the motion of an entire nanostructure.

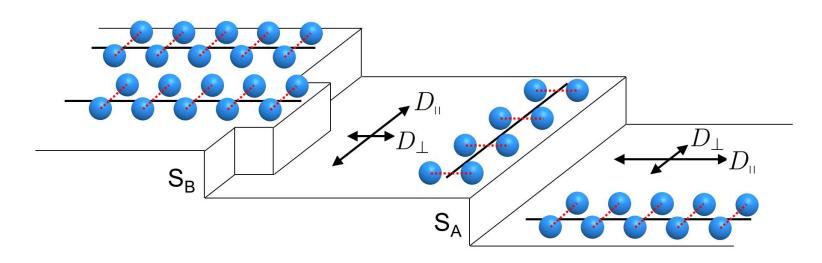


While it has been neglected in most studies, the **crystalline anisotropy** of the surface may play an important role on adatom motion and therefore on nanostructure motion. We have used Low Energy Electron Microscopy (LEEM), to observe Si(100) surfaces in-situ and in real time with high temporal and spatial resolution, and in a large temperature range (1000-1500 K).

In order to support the experimental results and obtain more insights in the motion mechanism, we have developed a **Kinetic Monte Carlo model** based on both anisotropic and electromigration-biased diffusion at surfaces.

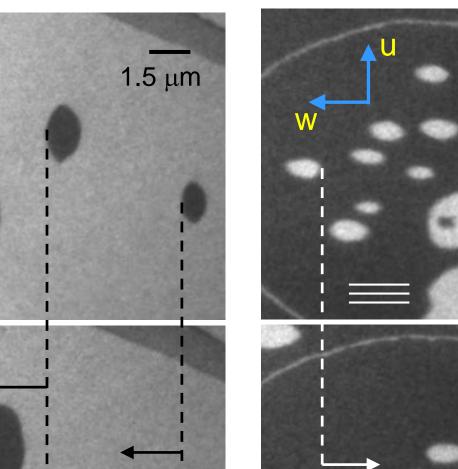
5 nm lateral resolution Electron energy lower than 20 eV High imaging dynamics (0.1 s per image) atomic vertical resolution

## Si(100) surface reconstruction



The Si(100) surface structure has dimer rows running perpendicularly on alternating terraces. Diffusion is faster along dimer rows than perpendicularly to them

# Displacement of 2D voids under electromigration (EM)

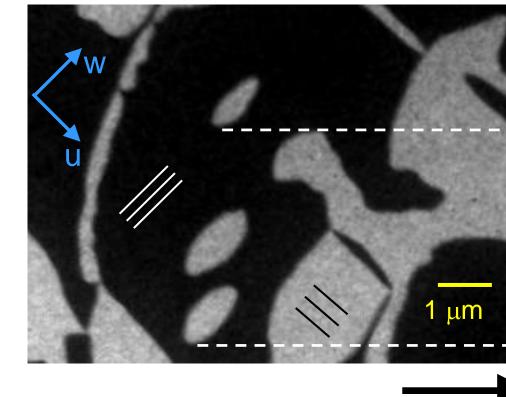


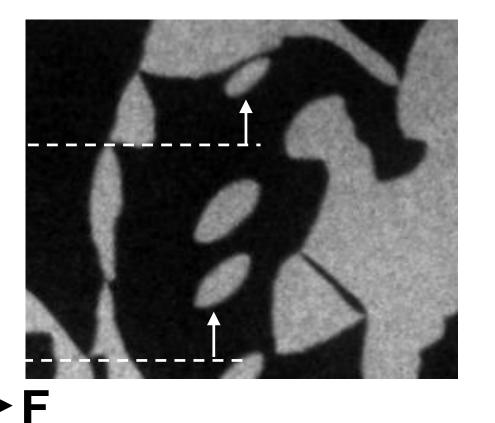
The **shape** of the voids depends on the orientation of the dimer rows of the upper terrace (outside the voids)

Voids elongated perpendicularly to the EM force move opposite to the force

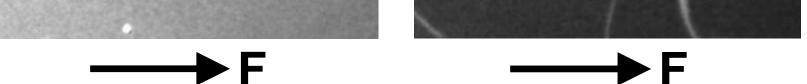
Voids with shape parallel to the force move in the same direction of the

## Current at **45°** from the dimer rows

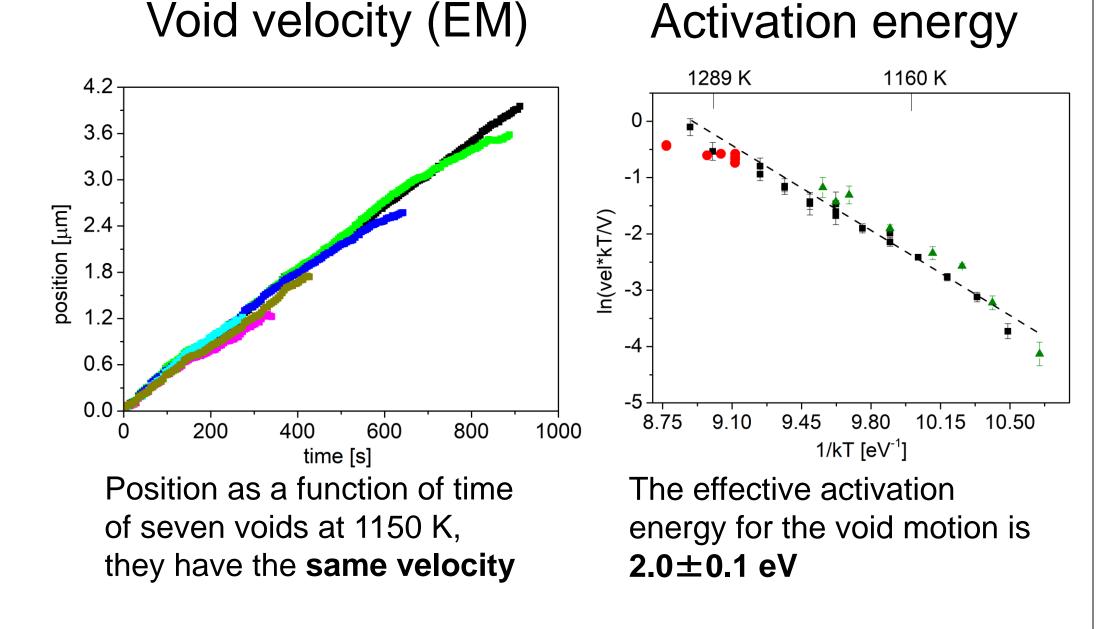




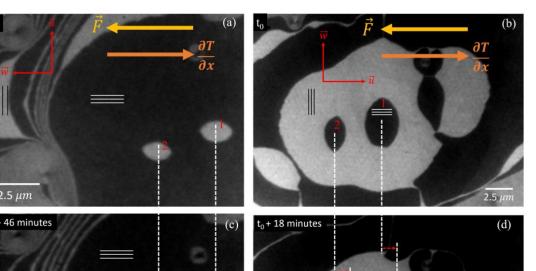
With a force applied from left to right, the voids move towards the top, at 90° from the electric-field direction and 135° from the [011] axis



## KMC simulations



Displacement of voids under thermomigration



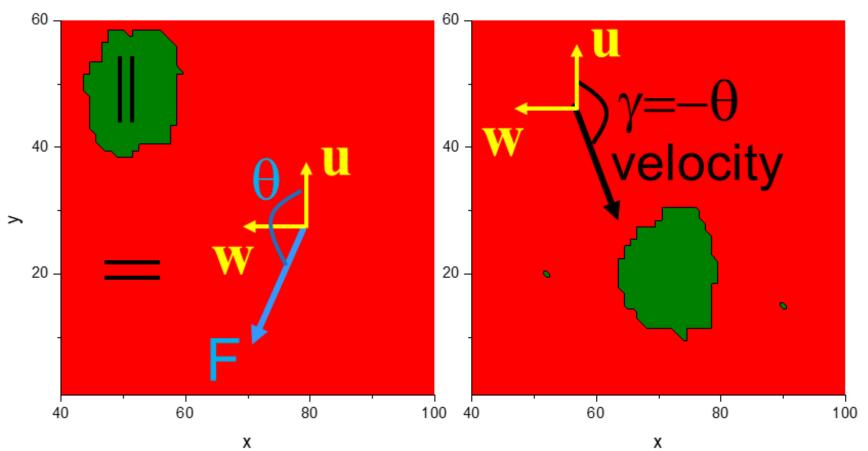
thermomigration (TM), the left side is colder than the right side

force

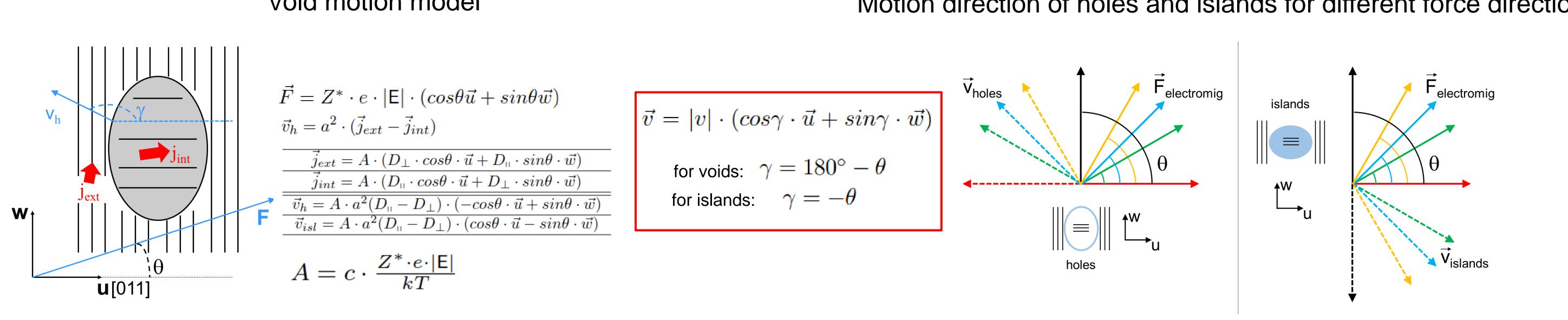
Ad-dimers (presumed mobile species) move from the hot to the cold side

2D voids moving under

Motion of voids and islands similar to EM



Kinetic MonteCarlo simulations taking into account the dimer rows and the diffusion anisotropy **reproduce all** the observed behaviors of void and island motion



Void motion model

Motion direction of holes and islands for different force directions

#### Schematics of a 2D void.

The dimer rows inside the hole are oriented horizontally, in the same direction of **u**. The force exerted by the electric field is oriented along the blue arrow and forms an angle  $\theta$  with **u**.

#### The void displaces in a direction forming an angle $\gamma$ with **u**.

J<sub>ext</sub> and J<sub>int</sub> are the atomic fluxes at the exterior and at the interior of the void. D are diffusion coefficients parallel and perpendicular to dimer rows; v are hole and island velocities; a is an atomic length; c is the concentration of diffusion species

### Conclusions

- The motion of nanostructures on Si(100) is possible thanks to the difference of diffusion coefficient parallel or perpendicular to dimer rows.
- The effective activation energy for the motion of 2D islands and voids at Si(100) surfaces is  $2.0 \pm 0.1$  eV, given by the sum of a diffusion energy and a creation energy of the diffusing species

This work was performed in the framework of the ANR grant HOLOLEEM (ANR-15-CE09-0012). We are grateful to B. Ranguelov and M. Michailov for stimulating discussions had in the framework of the PHC Rila project (38663TB)) project. The poster is based on the paper: "2D nanostructure motion on anisotropic surfaces controlled by electromigration", S. Curiotto, P. Müller, A. El-Barraj, F. Cheynis, O. Pierre-Louis, and F. Leroy, Applied Surface Science, vol. 469 (2019) 463-470